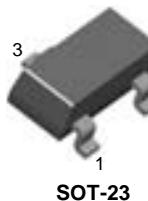
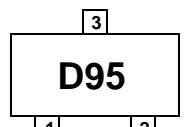


# **BAR43/A/C/S**

## **Schottky Rectifiers**



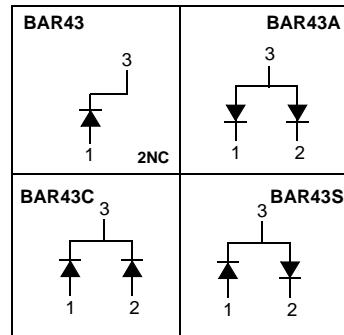
**SOT-23**



**D95**

**MARKING**  
BAR43 D95 BAR43A DB1  
BAR43C DB2 BAR43S DA5

**Connection Diagram**



### **Absolute Maximum Ratings \*** $T_a = 25^\circ\text{C}$ unless otherwise noted

<b>Symbol</b>	<b>Parameter</b>	<b>Value</b>	<b>Units</b>
$V_{RRM}$	Maximum Repetitive Reverse Voltage	30	V
$I_{F(AV)}$	Average Rectified Forward Current	200	mA
$I_{FSM}$	Non Repetitive Peak Forward Current Pulse Width = 1.0 second	750	mA
$T_{STG}$	Storage Temperature Range	-55 to +150	$^\circ\text{C}$
$T_{Jmax}$	Operating Junction Temperature	150	$^\circ\text{C}$

\* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

### **Thermal Characteristics**

<b>Symbol</b>	<b>Parameter</b>	<b>Value</b>	<b>Units</b>
$P_D$	Power Dissipation	290	mW
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	430	$^\circ\text{C}/\text{W}$

### **Electrical Characteristics** $T_C = 25^\circ\text{C}$ unless otherwise noted

<b>Symbol</b>	<b>Parameter</b>	<b>Test Conditions</b>	<b>Min.</b>	<b>Max.</b>	<b>Units</b>
$V_R$	Breakdown Voltage	$I_R = 100\mu\text{A}$		30	V
$V_F$	Forward Voltage	$I_F = 2.0\text{mA}$ $I_F = 15\text{mA}$ $I_F = 100\text{mA}$	260	330 450 0.8	mV mV V
$I_R$	Reverse Leakage	$V_R = 25\text{V}$ $V_R = 25\text{V}, T_a = 100^\circ\text{C}$		0.5 100	$\mu\text{A}$ $\mu\text{A}$
$t_{rr}$	Reverse Recovery Time	$I_F = I_R = 100\text{mA}, I_{RR} = 1.0\text{mA}$ $R_L = 100\Omega$		5.0	ns
	Minimum Detection Recovery Time	$I_F = I_R = 100\text{mA}, I_{RR} = 1.0\text{mA}, R_L = 100\Omega$	80%		